Technion – Israel Institute of Technology

Write Once, Get 50% Free: Saving SSD Erase Costs Using WOM Codes

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Joint work with:

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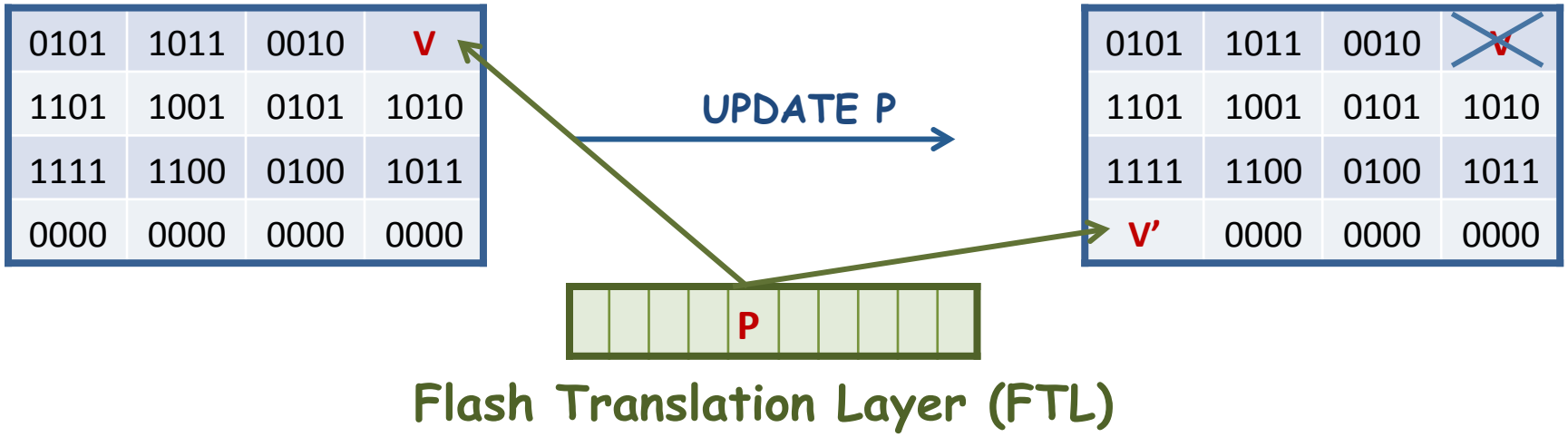
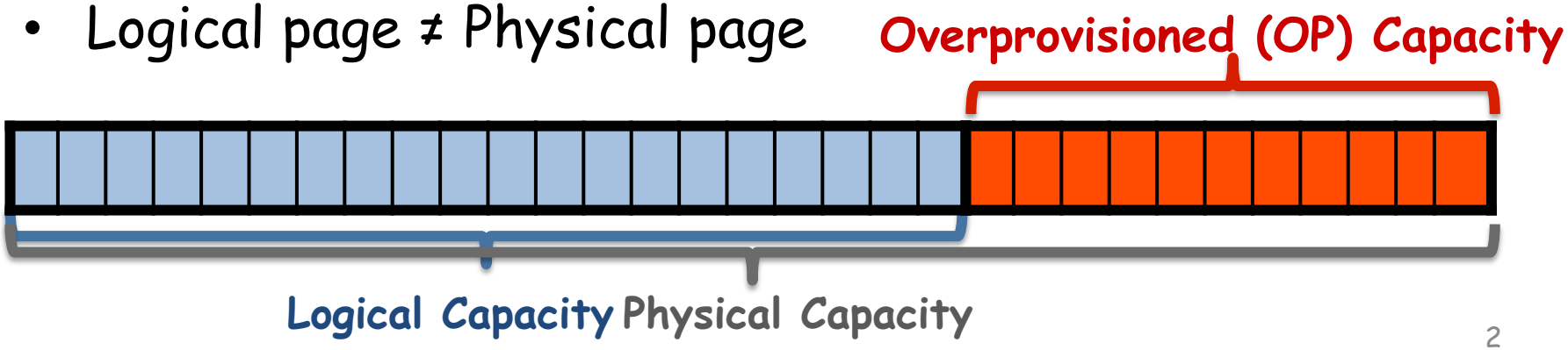
Flash in a Nutshell



- **Out of place writes** replace updates
- Logical page ≠ Physical page



Flash in a Nutshell

0101	A	0010	B
1101	1001	0101	1010
1111	1100	C	1011
0010	0011	0100	D

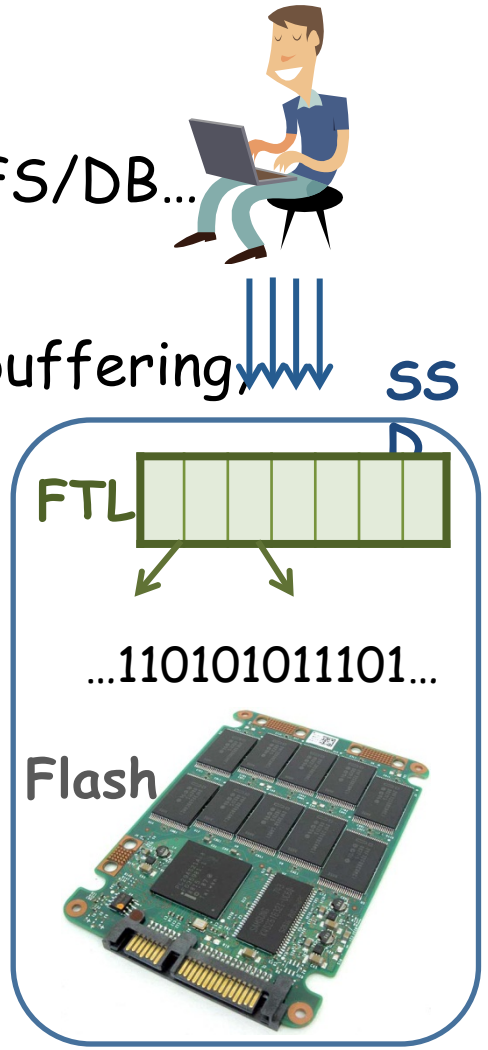
Garbage Collection →

A	B	C	D
0000	0000	0000	0000
0000	0000	0000	0000
0000	0000	0000	0000

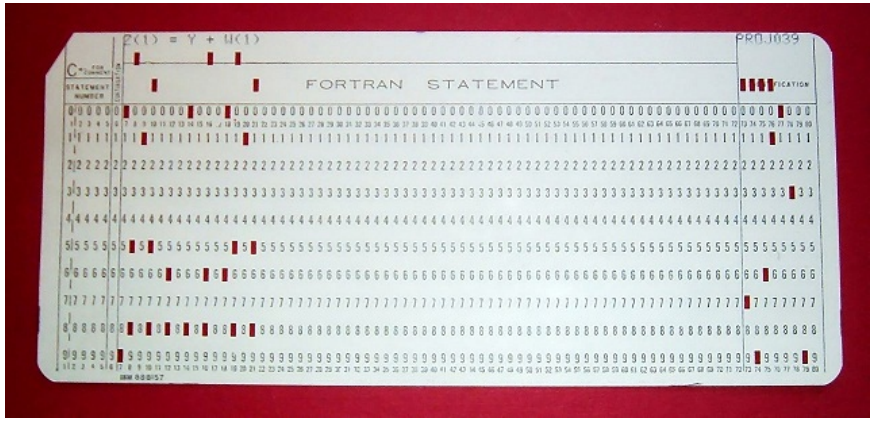
- **Garbage Collection (GC)** generates extra writes
- Write Amplification (WA) =
  (user writes + GC writes)/user writes
- Larger OP ➔ Lower WA ➔ Less erasures

How to extend SSD Lifetime?

- User level
  - Caching, admission control, specialized FS/DB…
- FTL
  - Wear leveling, throttling, partitioning, buffering, deduplication…
- Flash
  - Write voltage/speed…
- Code
  - Error correction
  - **WOM (write-once memory) codes overwrite without erasure**



Write-Once Memory Codes



data	1st write	2nd write
00	000	111
10	100	011
01	010	101
11	001	110

(Rivest and Shamir, 1982)

- WOM Code: write ***n* bits** of information on ***m* cells**, *n>m*
- Example: **write *11*** and then **write *01***
  - Normally:

1	1	0	1

  - WOM code:

1	0	1

Typical Use of WOM Codes

- User writes **logical** data pages
- Page size **increases** with encoding
- Invalid pages are 'reused' **without erasing**
- **Read** before the second write

[Grupp et. al., MICRO '09][Jagmohan et.al., MSST '10]
[Loujie et. al., GLOBECOM '12]
[Jacobvitz et.al., HPCA '13][Odeh and Cassuto, MSST '14]

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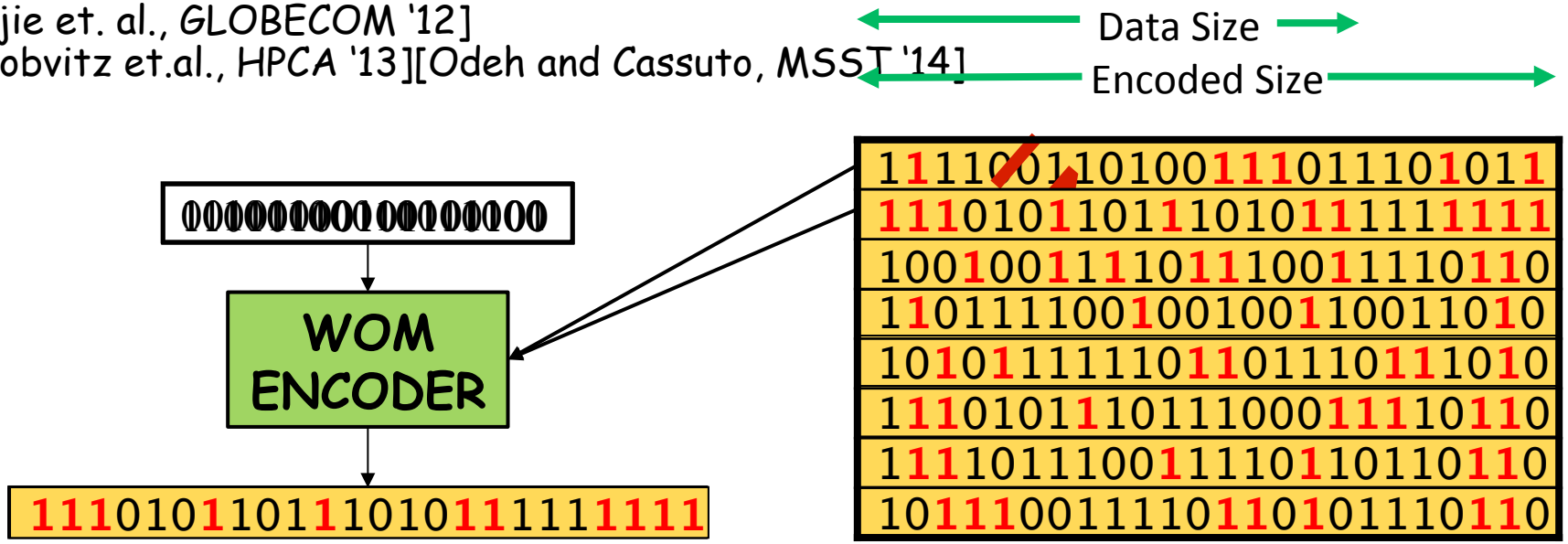
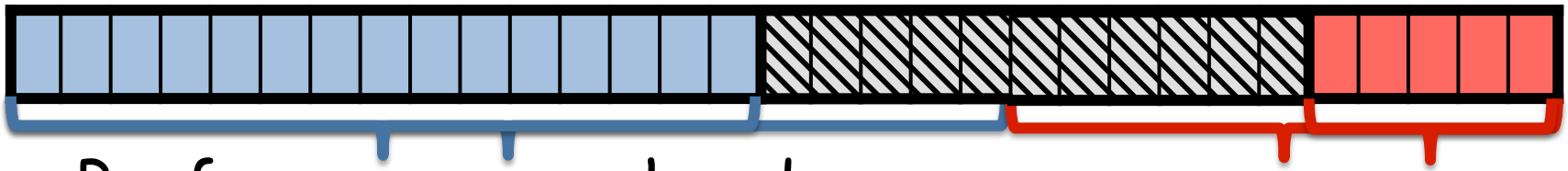


Drawbacks of Typical Use

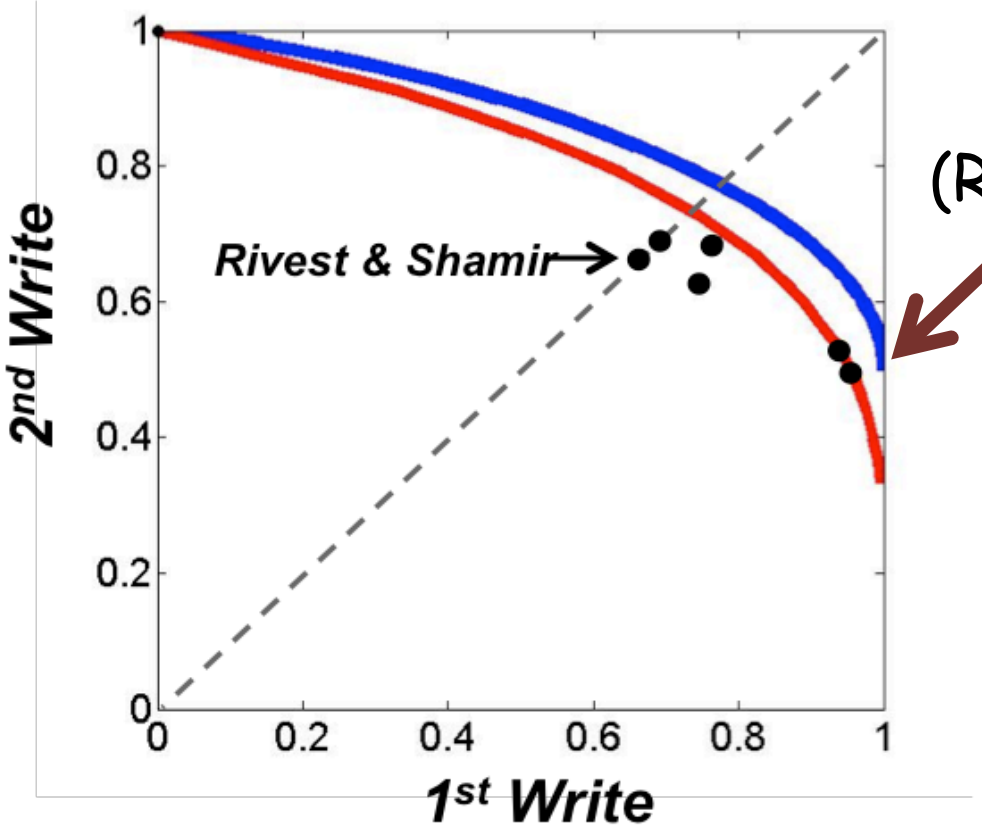
- Capacity overhead:
  - 29%-50% **additional storage** is needed for WOM coding



- Performance overheads:
  - I/O operations access 29%-50% **more bits**
  - A **read precedes** every second write
- Compatibility:
  - **Requires modification** in physical page size
  - Or access 2 physical pages

Our Approach

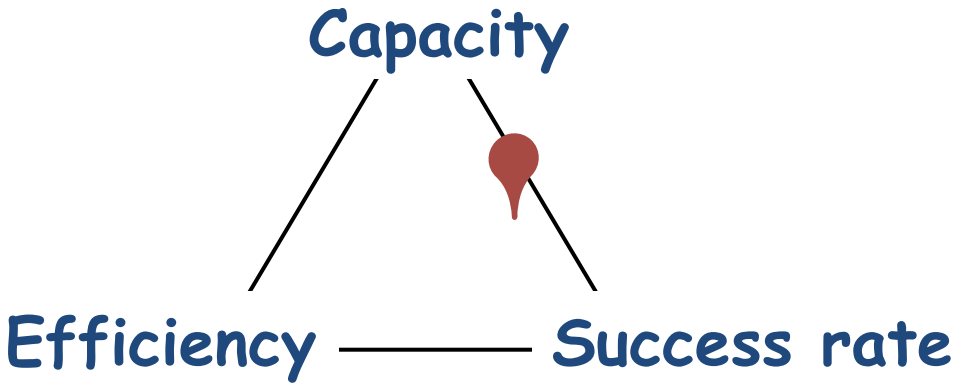
Capacity region of two-write WOM codes

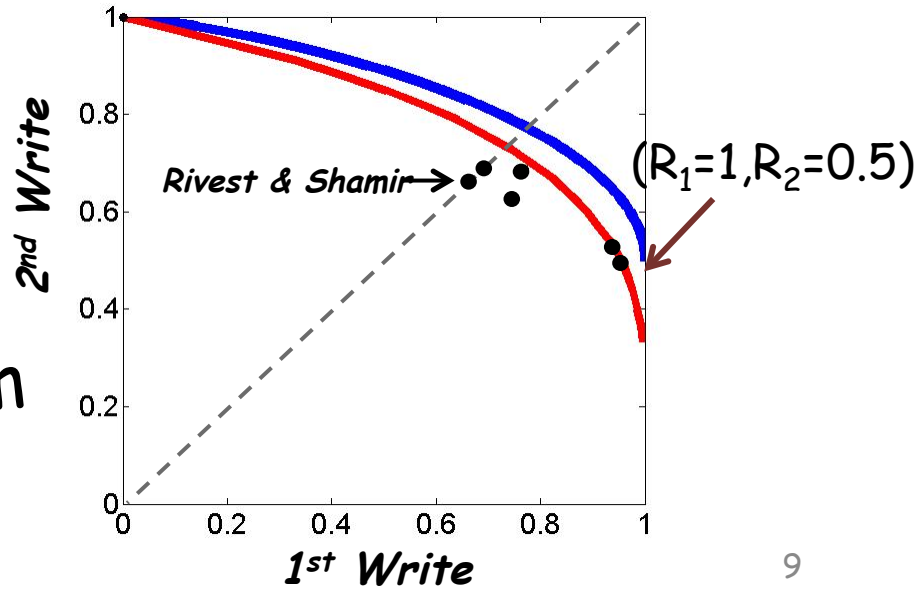


Yadgar, Yaakobi, Schuster, *Write once, get 50% free: Saving SSD erase costs using WOM code*, FAST '15

Our Approach

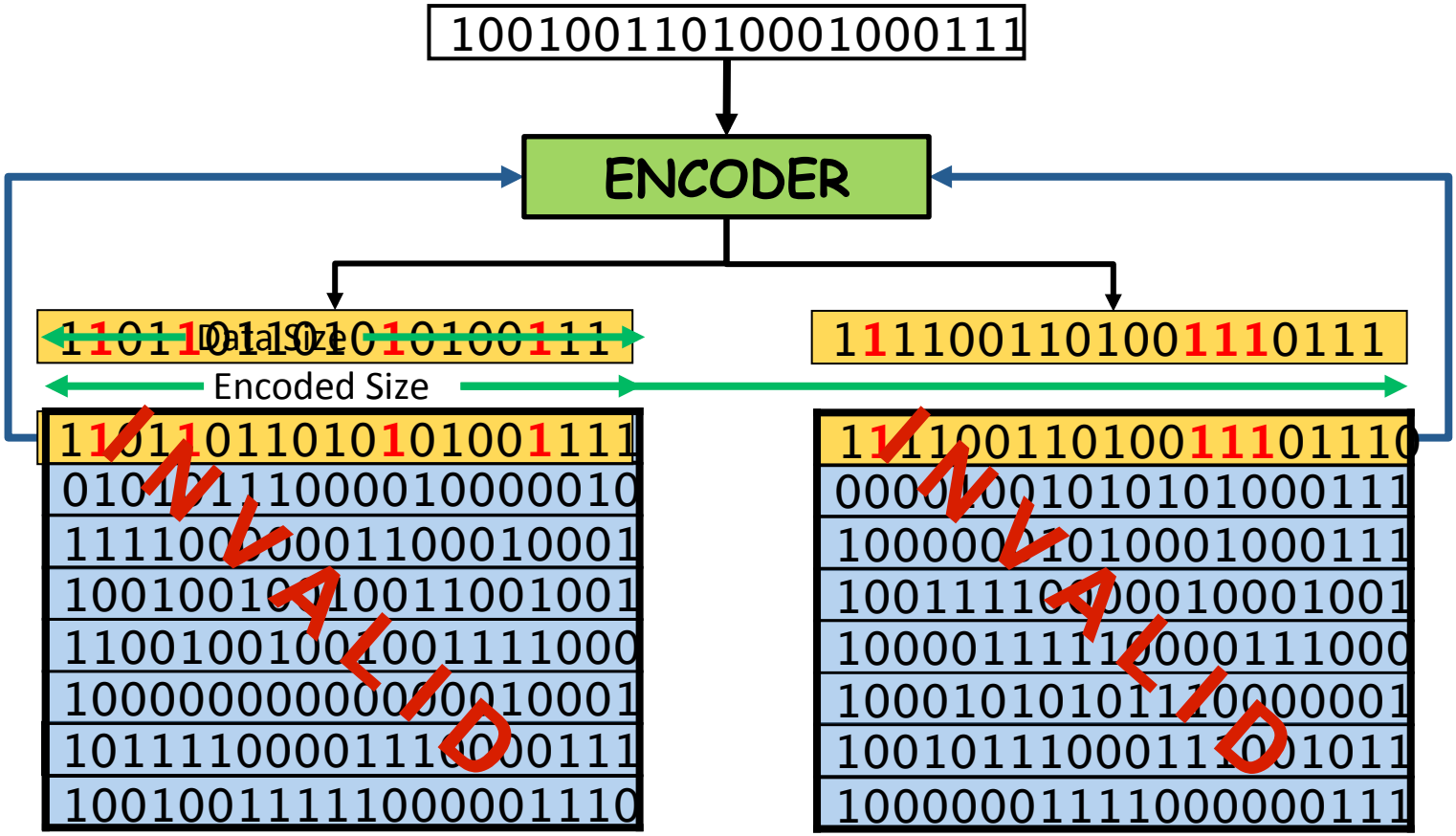
- Do not touch:
  - Interface
  - Complexity
  - Logical capacity
- Design handles:
  - Failures → retry
  - Latency → parallelism





Reusable SSD

- **1st write**: (almost) unmodified → no overhead
- **2nd write**: one logical page → two physical pages



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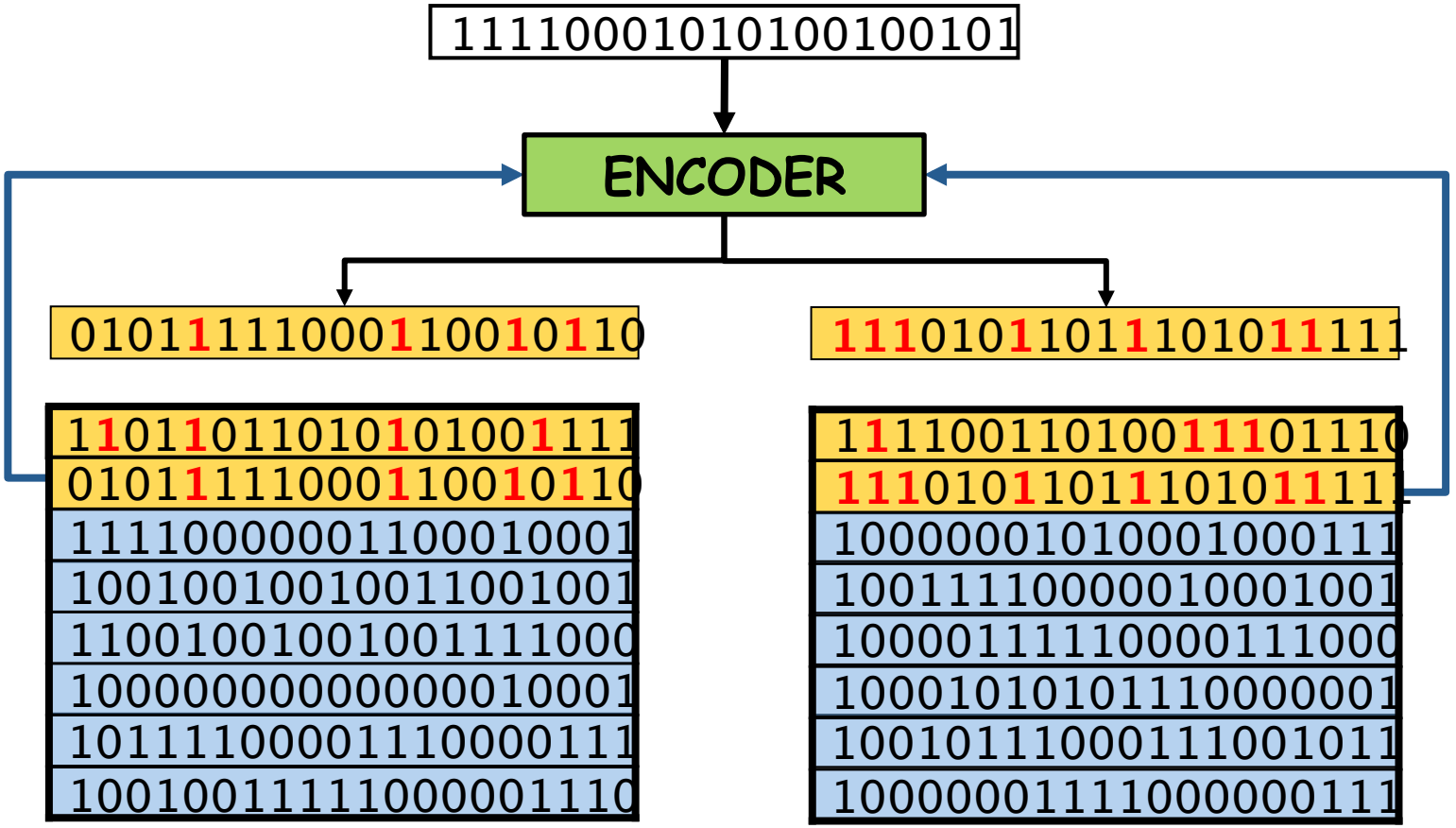

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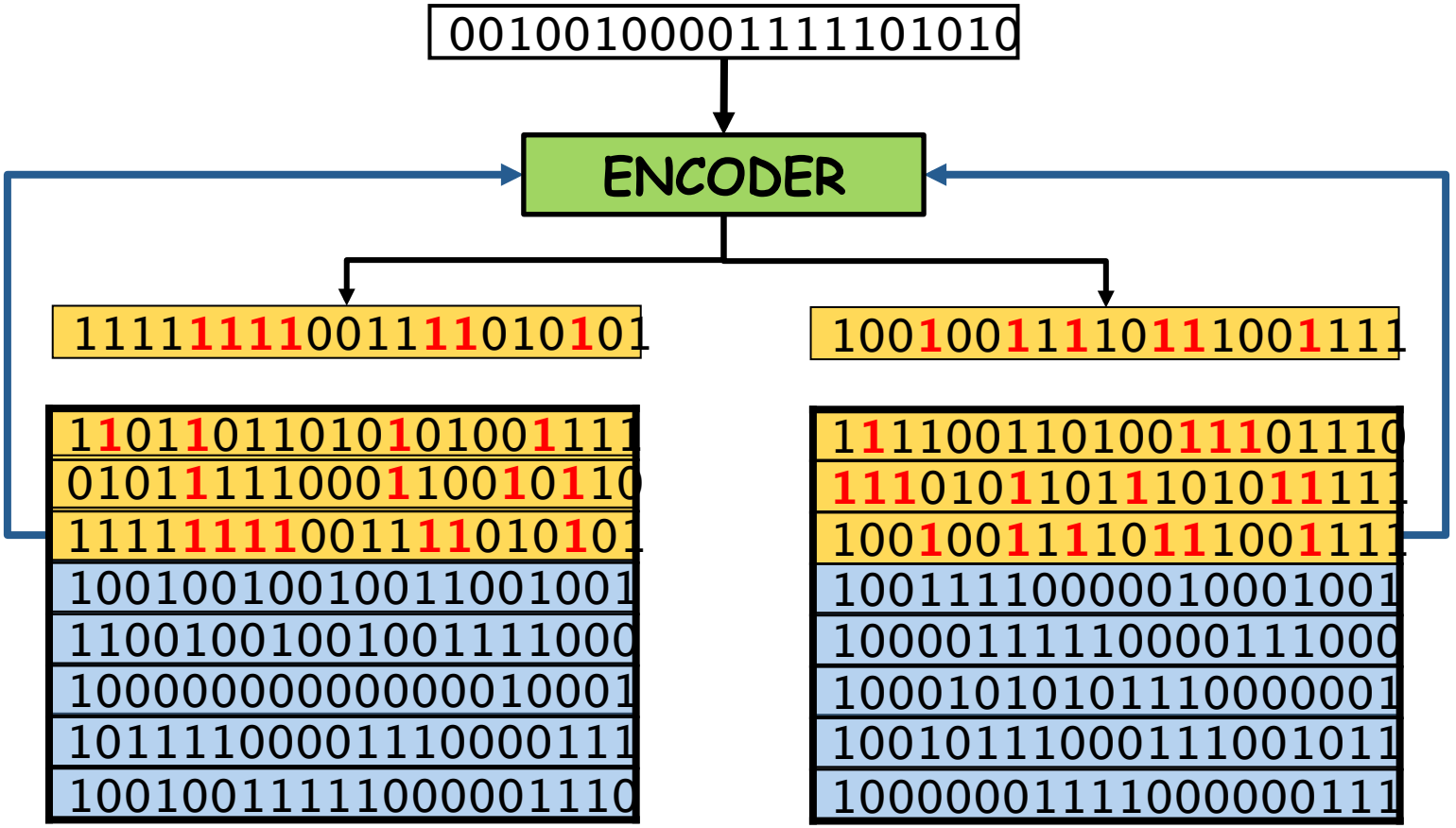

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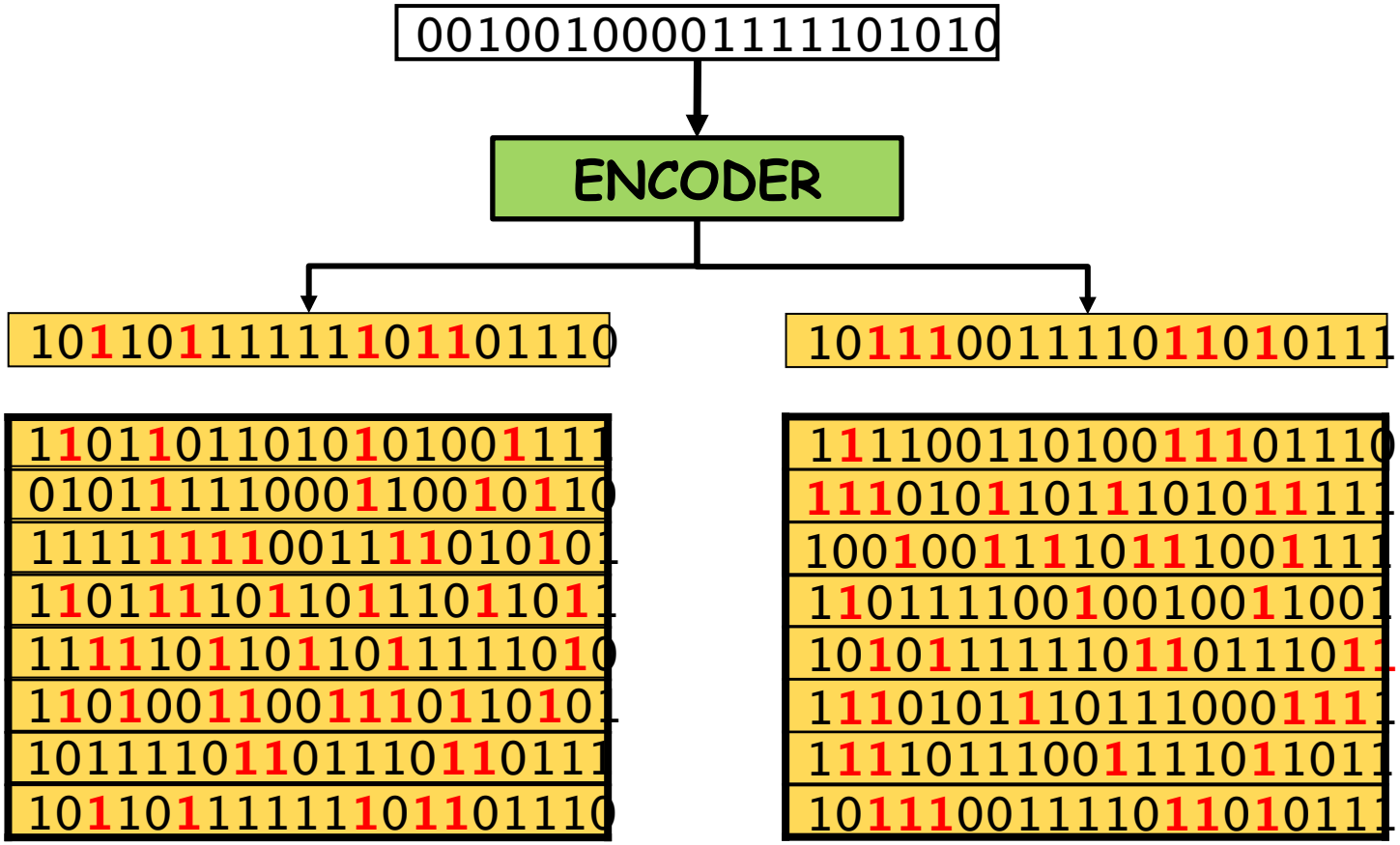
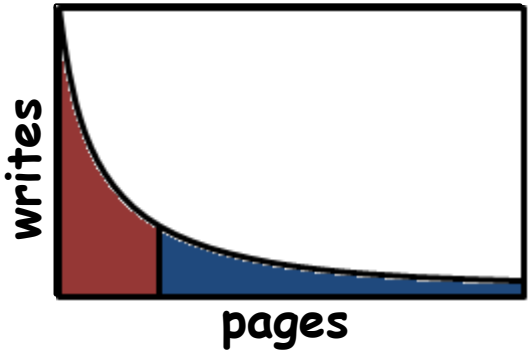
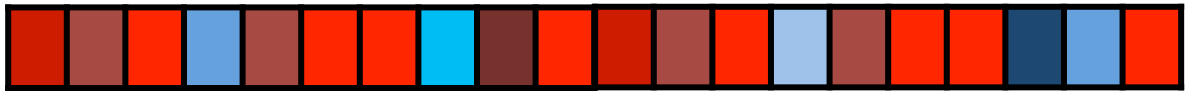


Hot/Cold Data

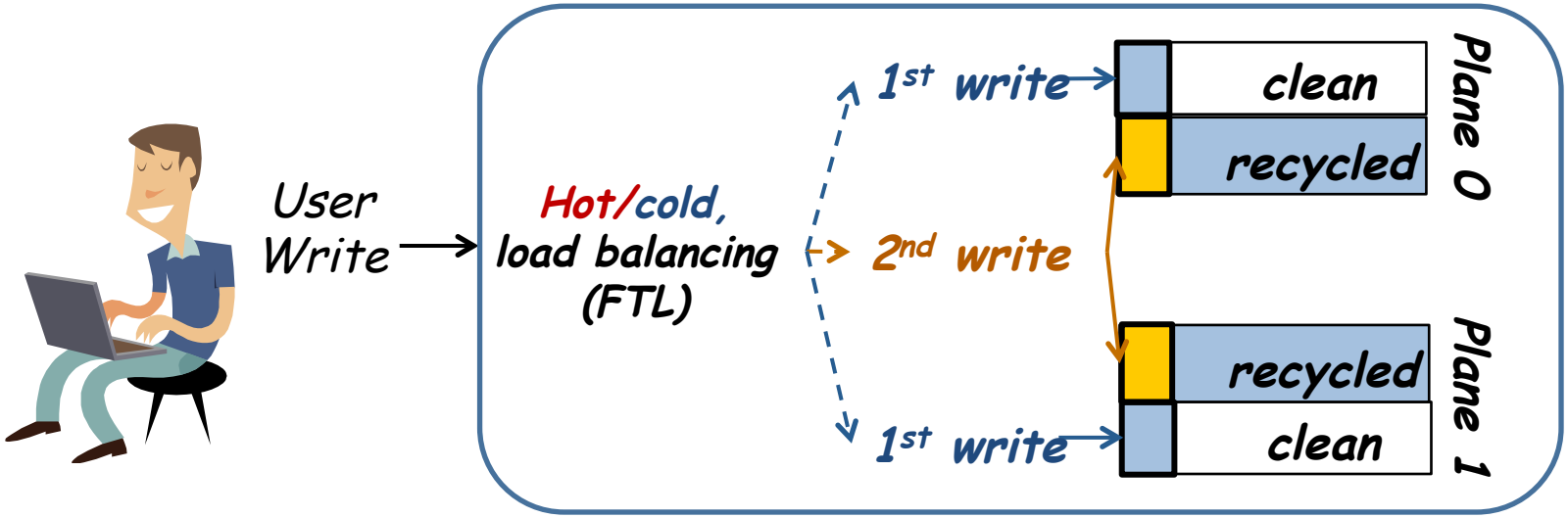
- First writes are more space efficient
  - →Best for long term storage
  - – ***Hot data***: will be overwritten soon
  - – ***Cold data***: will remain valid for long

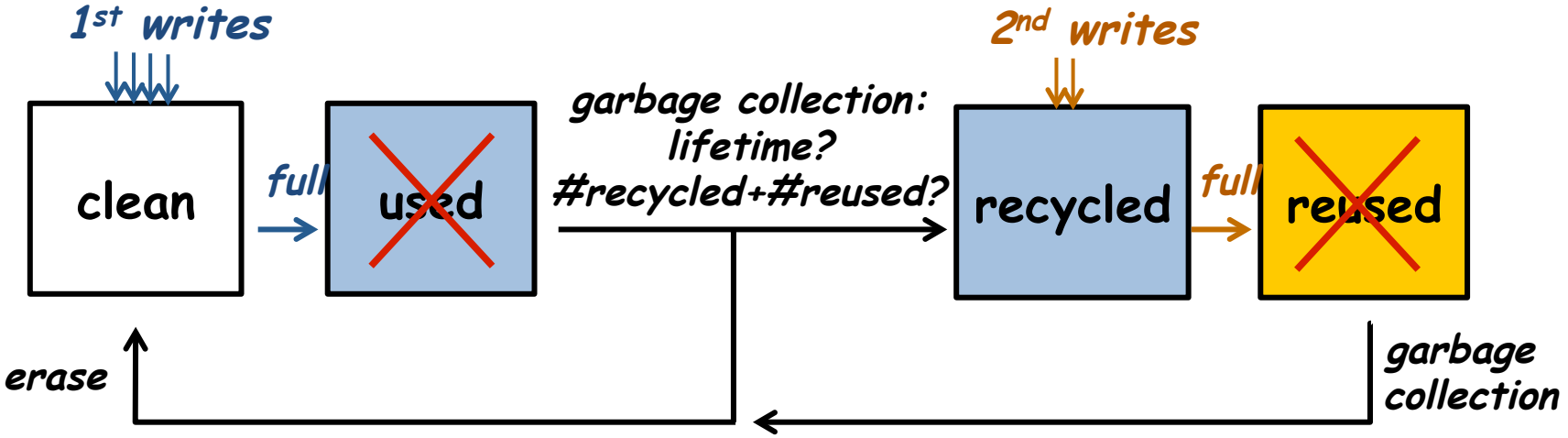




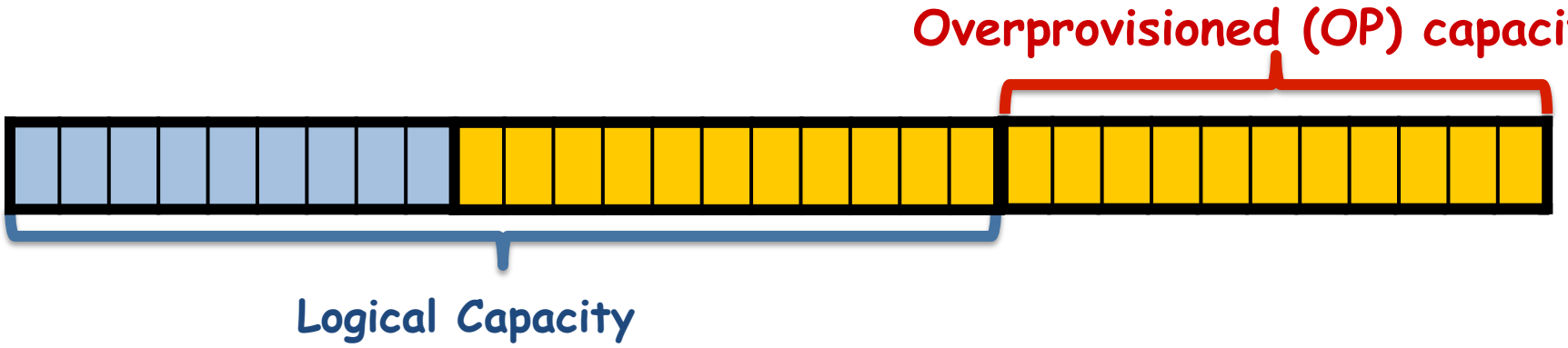
- Use second writes for hot pages
- Identify hot data according to I/O size
  - – Heuristic : **small → hot**, **large → cold**
  - – More accurate classifications available

Putting it All Together





Analysis



- Standard SSD (best case): $E = N/Z$

  Erasures = E, *Logical pages written* = N, *Pages per block* = Z

- Reusable SSD (best case): "write once, get 50% free"

$$E' = N/(Z+Z/2) = 2/3E$$

→ **33% reduction in erasures** (without GC)

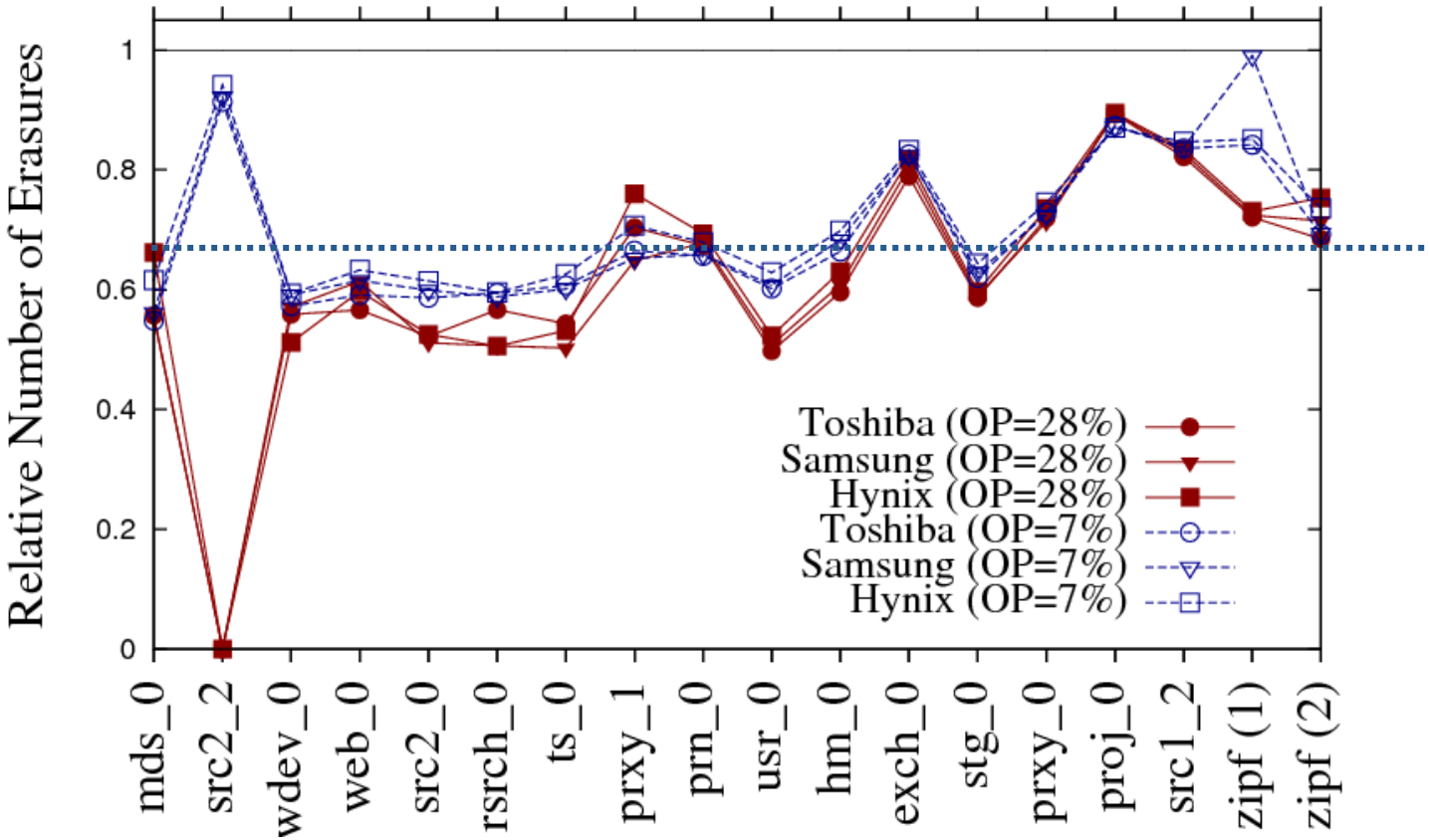
Evaluation

- How many **erasures** saved?
- How is **performance** affected?
- **Sensitivity** to design parameters

Type	Pgs/Blk	R (us)	W (ms)	E (ms)
SLC	64	30	0.3	3
MLC	128	200	1.3	1.5
MLC	256	80	1.5	5

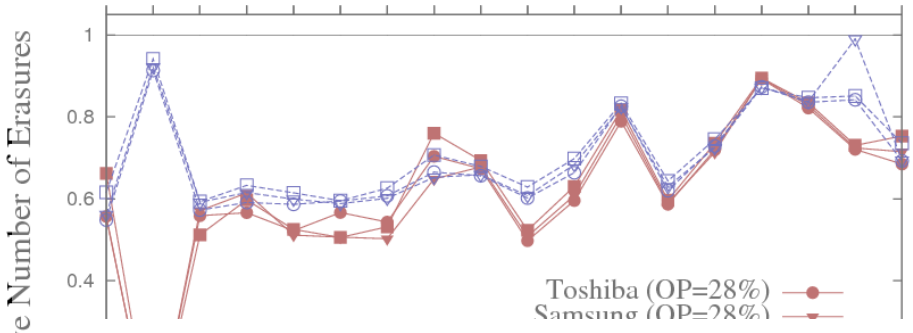
- DiskSim simulator
  - Available SSD extension
  - Modified FTL component
- Trace input:
  - Microsoft MSR + Exchange
  - Synthetic Zipf

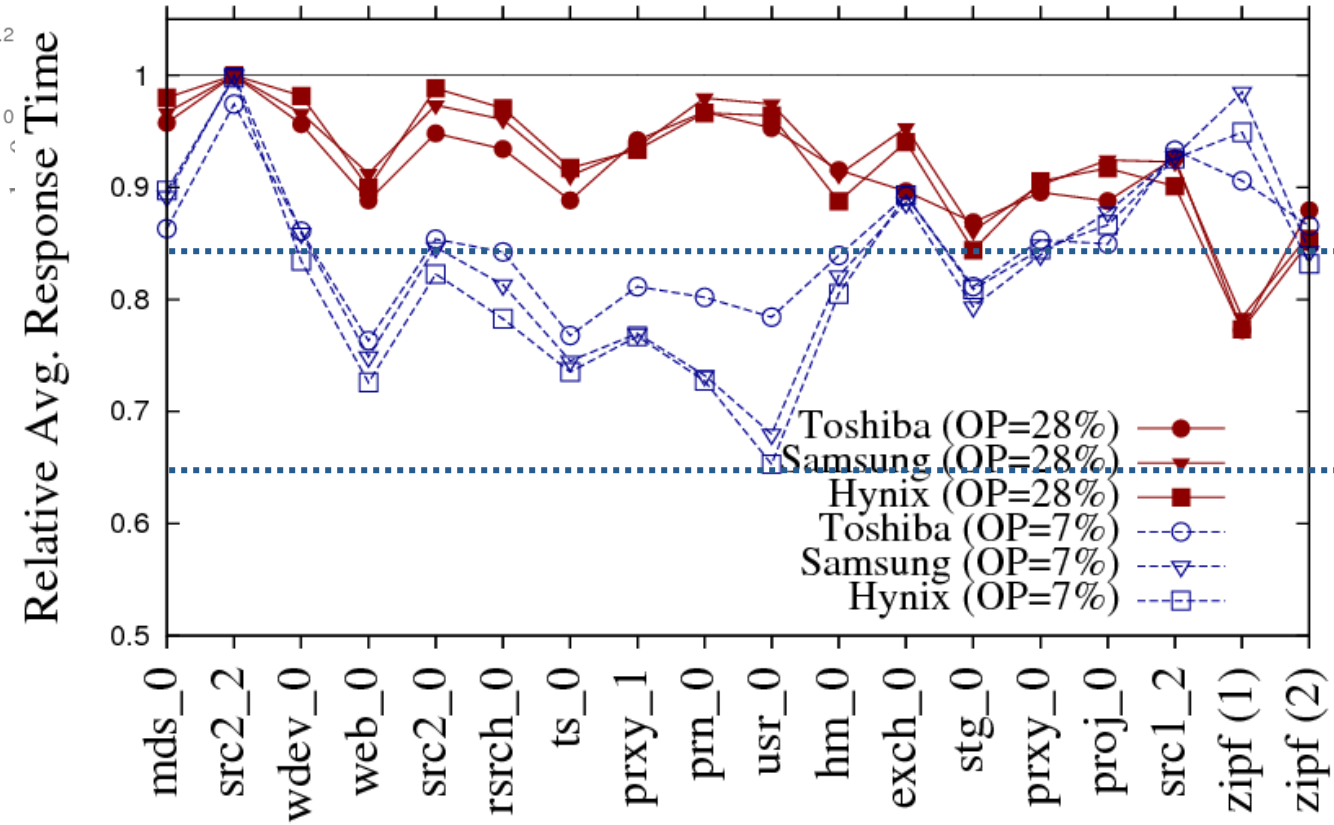
Erasures



Expected 33% reduction

Response Time



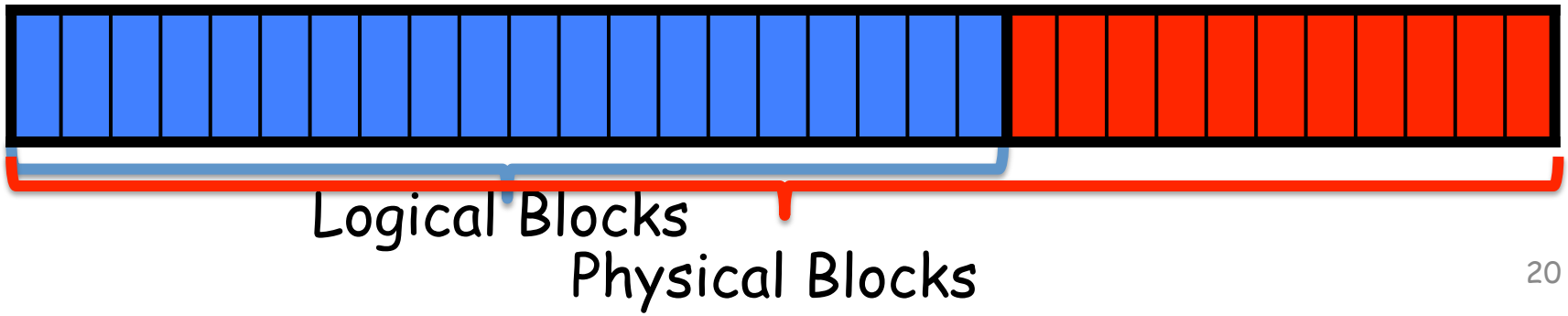


Enterprise: up to 15% reduction

Consumer: up to 35% reduction

Greedy Garbage Analysis

- **Write amplification** = $\frac{\#\text{ Physical writes}}{\#\text{ Logical writes}}$
- **Overprovisioning** = (T-U)/U ;
  T = #physical blocks, U = #logical blocks
- **Question**: How are the overprovisioning factor and write amplification related?
- **Theorem** [Hu & Haas '10]: Greedy garbage collection is optimal in order to reduce the write amplification (for uniform writing)



Greedy Garbage Analysis

- **Write amplification** = $\frac{\#\text{ Physical writes}}{\#\text{ Logical writes}}$
- **Overprovisioning** = (T-U)/U :
  T
- **Quest** nd write amplification related, ***under random uniform writing***?
  - **N** = #logical page writes ; **M** = # physical page writes
  - **E** = #block erasures = M/Z , **Z** = # pages in a block
- On average: **Y = α'Z** valid pages in an erased block
  - **M = N + EY**
  - E = M/Z = (N+EY)/Z; (Z-Y)E = N; E=N/(Z-Y);

E=N/Z(1-α')

Erasure Factor = 1/(1-α')

- **Question**: What is the connection b/w **α=U/T** and **α'=Z/Y**?
- **Answer**: α = (α'-1)/ln(α') (Menon '95, Desnoyers '12)

- Overprovisioning = (T-U)/U ;
  T = #physical pages, U = #logical pages
- Question: How are the overprovisioning factor and write amplification related, *under random uniform writing*?
  - N = #logical page writes ; M = # physical page writes
  - E = #block erasures = M/Z , Z = # pages in a block
- On average: Y = α'Z valid pages in an erased block
  - M = N + EY
  - E = M/Z = (N+EY)/Z; (Z-Y)E = N; E=N/(Z-Y); **E=N/Z(1-α')**
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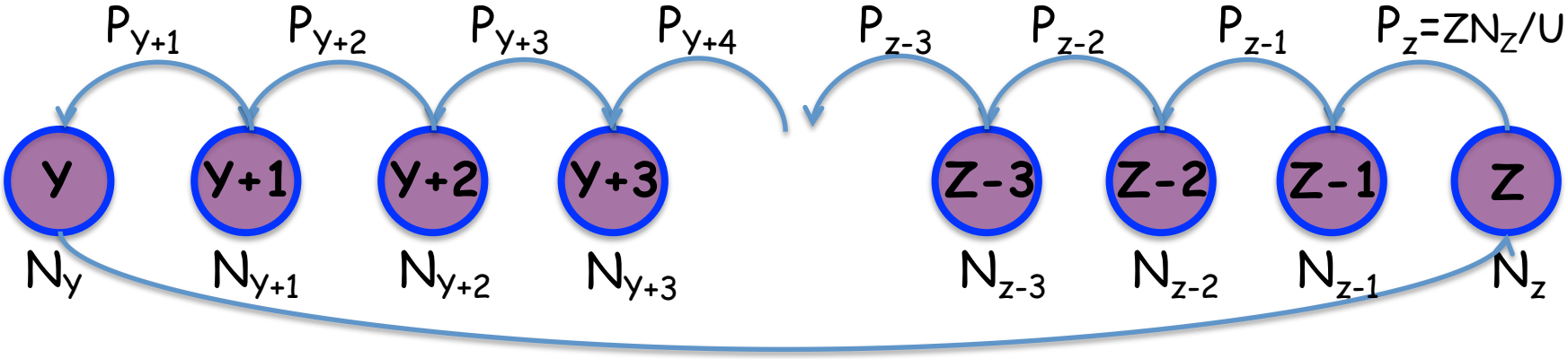


This process forms a Markov chain which will be in a **steady state**

N_i = # of blocks with i valid logical pages

P_i = the prob for a block to move from state i to state i-1 = iN_i/U

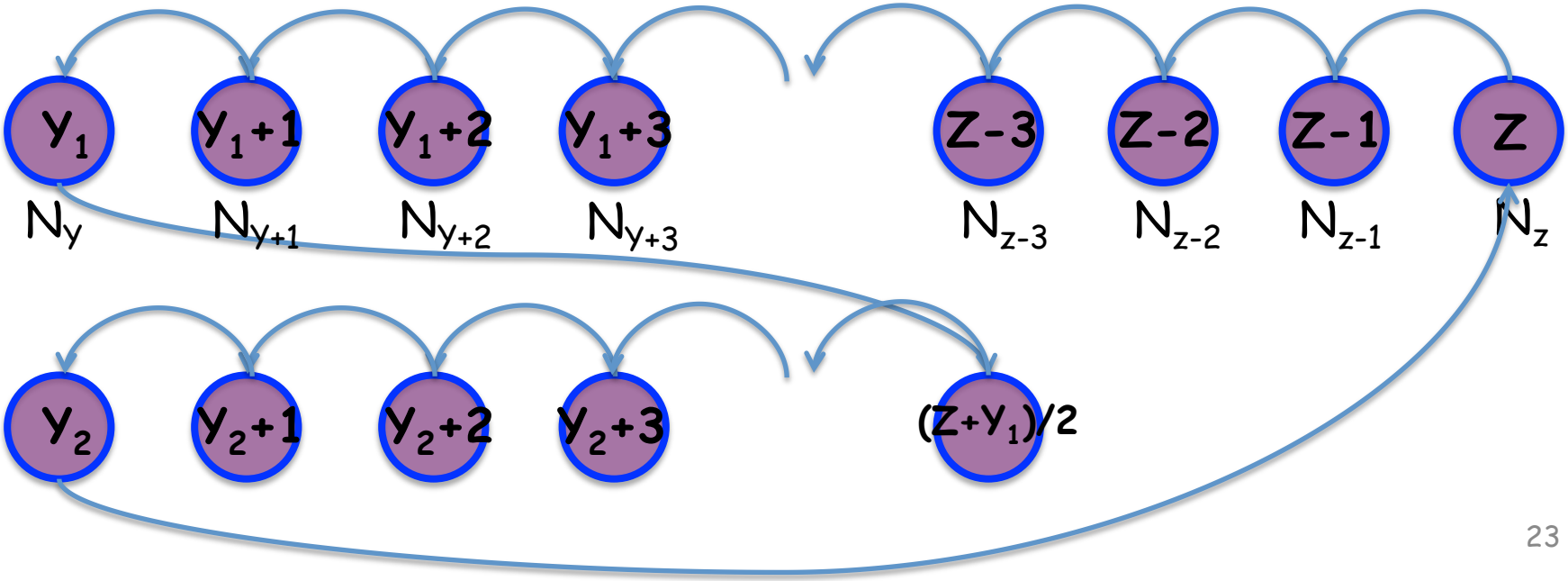
Key property: The number of **pages** in every state is (roughly) fixed

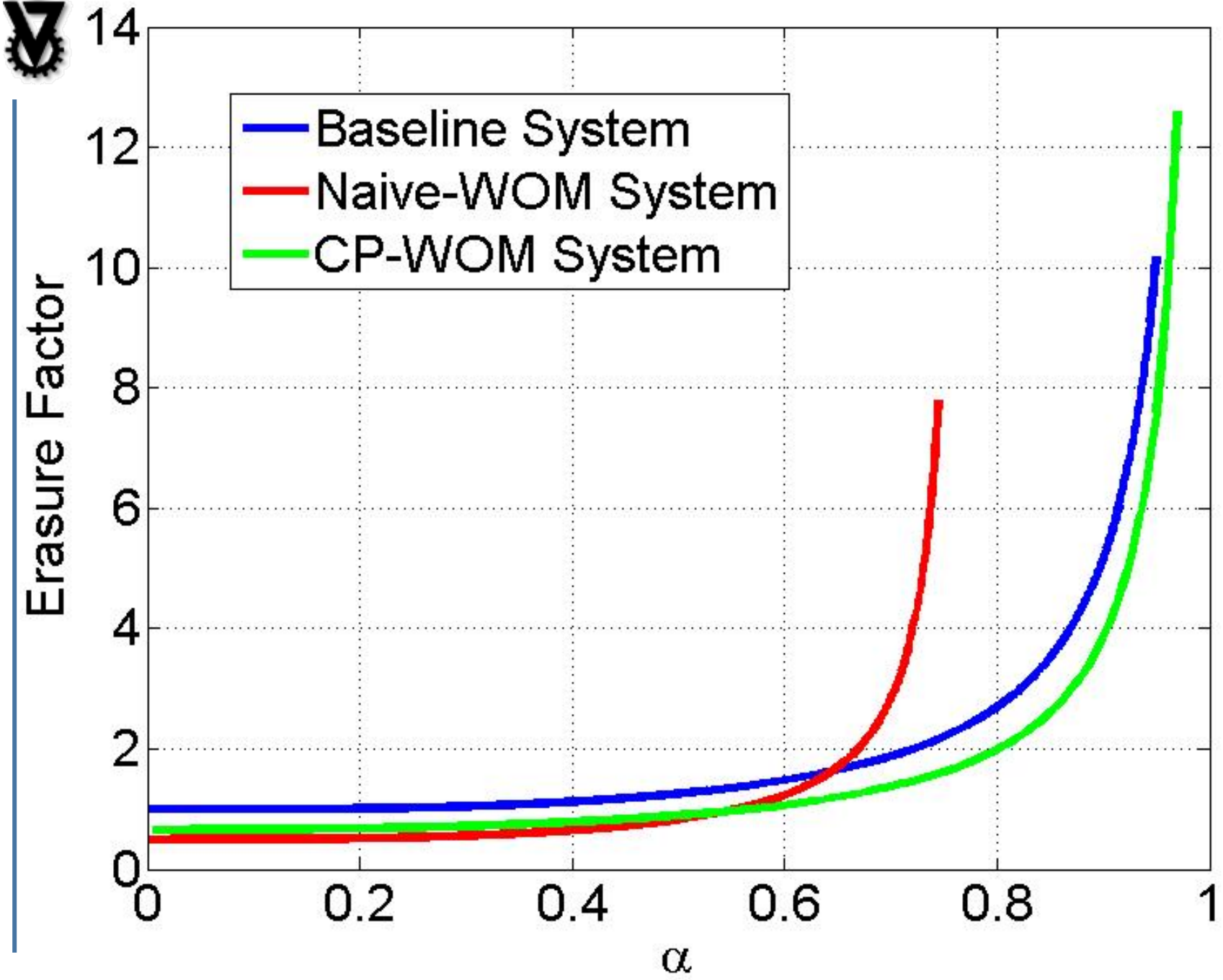
$$i \bullet N_i = \text{constant}$$

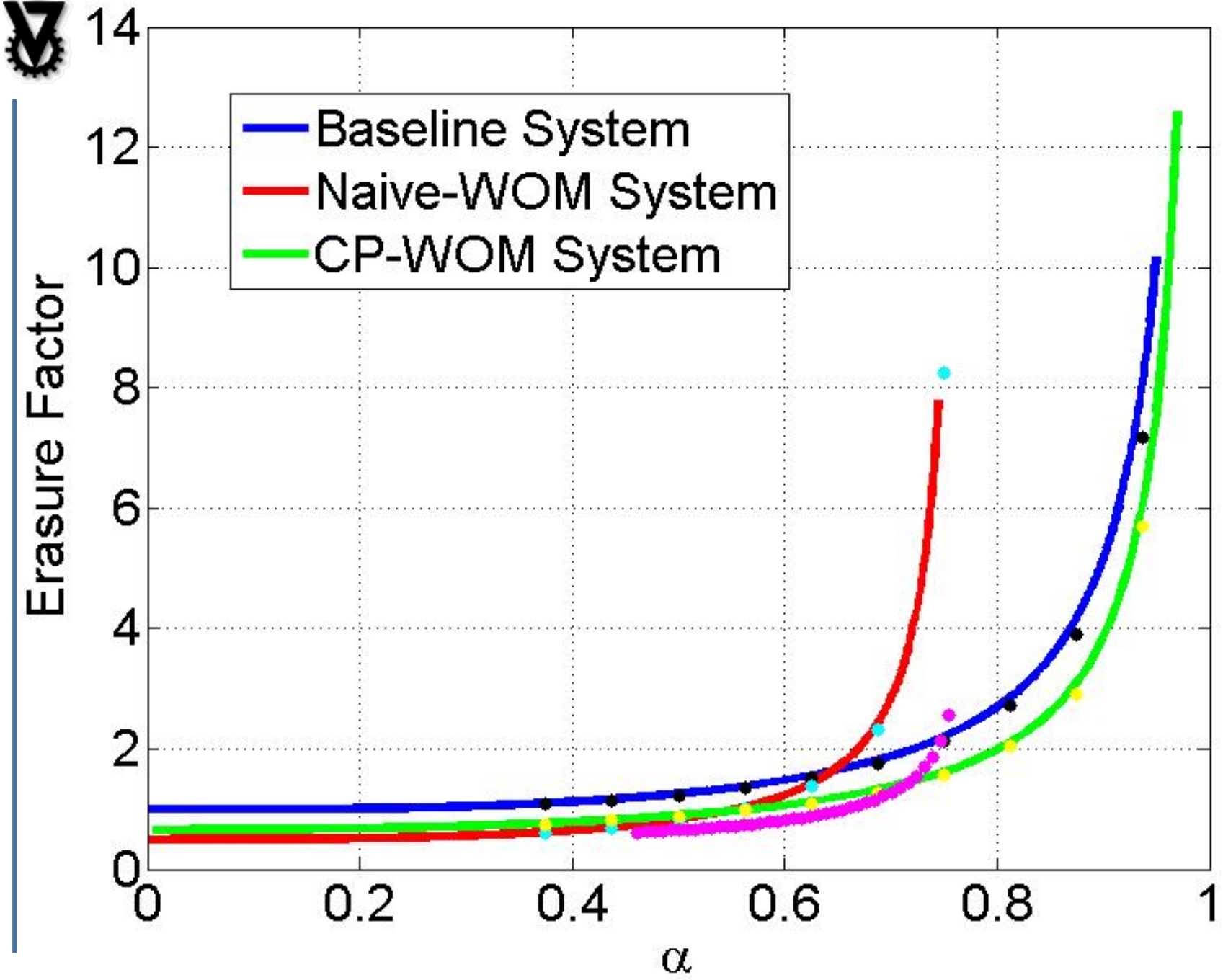
$$\alpha = U/T = \cdots \approx (Z-Y)/(Z\ln(Z/Y)) = (Y/Z-1)/\ln(Z/Y) = (\alpha'-1)/\ln(\alpha')$$

Analysis of Reusable SSD

- Blocks can be in 2 different states: first or second write
- **GC algorithm**: characterized by a parameter γ_1 –
  - B_1, B_2: the blocks with min number of valid pages on a 1st, 2nd write
  - If the number of valid pages in B_1 is at most $Y_1=\gamma_1 \cdot Z$, move the block to 2nd write
  - Otherwise, erase the block B_2 and copy its valid pages




Baseline System
Naive-WOM System
CP-WOM System
Erasure Factor
α
0
2
4
6
8
10
12
14
0
0.2
0.4
0.6
0.8
1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0.8
1

Summary

- An **applicable** design of re-writes in SSD
  - Unmodified logical capacity
  - No hardware modification
  - Efficient encoding
- Erasures analysis
  - Up to **50% additional free writes**
  - Studying the improvement in erasure factor via WOM codes
  - Extensions for multiple writes
- More to be done
  - Improved codes
  - Multiple writes
  - Analysis of different workloads
  - Understanding the rewriting effect on the memory lifetime

Thank you!